ASSP for Image Processing

CMOS

A/D Converter (1-channel, 8-bit, 20MHz)

MB40C568

■ DESCRIPTION

The MB40C568 is a high-speed A/D converter using high-speed CMOS process technology.

■ FEATURES

· Resolution: 8 bits

• Linearity error: ±0.20% (Typ.)

Maximum conversion rate: 20 MSPS (Min.)

Power supply voltage: Analog section +5.0 V

Digital section +3.0 V or +5.0 V

Digital input voltage range: TTL level

• Digital output voltage range: CMOS level compatible

• Analog input voltage range: 0.5 to 4 V (with 2 Vp-p)

• Analog input capacity: 15 pF (Typ.)

• Power consumption: 50 mW (Typical:@fclk = 20 MHz, AVDD = 5 V, DVDD = 3 V)

60 mW (Typical: @fclk = 20 MHz, AVDD = DVDD = 5 V)

• Additional function: Reference voltage generator circuit: VREFT = 3 V, VREFB = 1 V

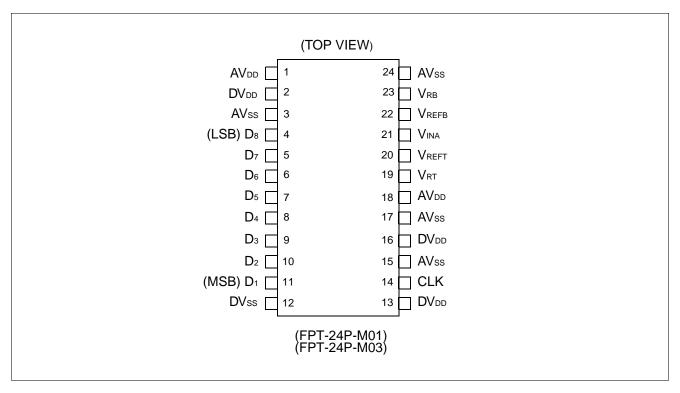
Package options: SOP24, SSOP24

■ PACKAGES



This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Pin name	Functions
1, 18	AV _{DD}	Analog power supply pins (+5 V)
2, 13, 16	DV _{DD}	Digital power supply pins (+3 or +5 V)
3, 15, 17, 24	AVss	Analog power ground pins (0 V)
12	DVss	Digital power ground pin (0 V)
4 to 11	D ₁ to D ₈	Digital output pins. D ₁ : MSB, D ₈ : LSB
14	CLK	Clock input pin
21	VINA	Analog input pin. Input range: VRB to VRT (2 Vp-p between 0.5 to 4 V)
19	V _{RT}	Reference voltage input pin (3 V)
20	VREFT	Reference voltage output pin. When connected to VRT, the pin generates $0.6 \times \text{AV}_{\text{DD}}$ (3 V).
23	V _{RB}	Reference voltage input pin (1 V)
22	VREFB	Reference voltage output pin. When connected to VRB, the pin generates $0.2 \times \text{AV}_{\text{DD}}$ (1 V).

Values within () are typical values.

■ NOTES ON USE

- Be sure to bypass the AV_{DD}, DV_{DD}, V_{RT} and V_{RB} pins to the ground using a high-frequency capacitor. The high-frequency capacitor should be connected as near the pin as possible.
- Provide four clocks or more immediately after the power up to prevent current dissipation due to the indeterminate internal logic.

■ ABSOLUTE MAXIMUM RATINGS (See WARNING)

Parameter	Symbol	Ra	Unit	
rarameter	Symbol	Min.	Max.	Ullit
Power supply voltage	AV _{DD} , DV _{DD}	-0.3	7.0	V
Input voltage	CLK, VINA VRT, VRB	-0.3	AVpp+0.3	V
Output voltage	D ₁ to D ₈	-0.3	DV _{DD} +0.3	V
Storage temperature	Tstg	- 55	+125	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Cumbal		Value		Unit
Farameter	Symbol	Min.	Min. Typ.		Onit
Analog input voltage	VINA	V _{RB}	_	V _{RT}	V
Analog reference voltage: T	V _{RT}	-	-	4.00	V
Analog reference voltage: B	V _{RB}	0.50	_	_	V
Analog reference voltage range	V _{RT} -V _{RB}	1.90	2.00	2.10	V
Digital "H" level input voltage	VIHD	2.4	_	_	V
Digital "L" level input voltage	VILD	-	-	0.8	V
Digital input current	I _{ID}	_	_	5	μΑ
Clock frequency	fclk	0.1	_	20	MHz
Minimum "H" level clock pulse width	tw+	22.5	_	_	ns
Minimum "L" level clock pulse width	tw-	22.5	-	-	ns
Operating temperature range	Та	-20	-	70	°C

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

(Continued)

MB40C568

(Continued)

• When using a single power supply

Parameter	Symbol		Value		Unit	
r ai airietei	Symbol	Min.	Тур.	Max.	Onit	
Power supply voltage	AV_{DD}, DV_{DD}	4.75	5.00	5.25	V	

When using dual power supplies

Parameter	Symbol		Unit		
Farameter	Syllibol	Min.	Тур.	Max.	Onit
Dower aupply voltage	AVDD	4.75	5.00	5.25	V
Power supply voltage	DV _{DD}	2.70	3.00	3.30	V

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

■ ELECTRICAL CHARACTERISTICS (Using a Single Power Supply)

DC Characteristics

(1) Analog section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter		Symbol			Unit	
		Syllibol	Min.	Тур.	Max.	Onit
Resolution		_	_	8	_	bit
Linearity error	DC precision	LE	_	±0.20	±0.30	%
Differential linearity error	DC precision	DLE	_	±0.12	±0.20	%
Analog input capacity		CINA	_	15	_	pF
Reference voltage: T		VREFT	_	$0.6 \times AV_{DD}$	_	V
Reference voltage: B		VREFB	_	$0.2 \times AV_{DD}$	-	V
Reference current		I _{RB}	-16.0	-8.0	-2.0	mA
Analog power supply current		Aldd	_	8.0	14.0	mA
Digital power supply current		DIDD	-	4.0	7.0	mA

(2) Digital section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Offic
Digital "H" level output voltage	Vohd	4.2	_	DV _{DD}	V
Digital "L" level output voltage	Vold	-	_	0.4	V
Digital "H" level output current	Іон	-400	_	_	μΑ
Digital "L" level output current	Іоь	_	_	1.6	mA

(3) Switching section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol		Unit			
Farameter	Syllibol	Min.	Тур.	Max.	Offic	
Maximum conversion rate	fs	20	_	_	MSPS	
Digital output delay time	tpd	0	5	20	ns	

■ ELECTRICAL CHARACTERISTICS (Using Dual Power Supplies)

DC Characteristics

(1) Analog section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter		Symbol		Unit		
raiailletei	raiailleter		Min.	Тур.	Max.	Offic
Resolution		_	-	8	_	bit
Linearity error	DC precision	LE	_	±0.20	±0.30	%
Differential linearity error	DC precision	DLE	_	±0.12	±0.20	%
Analog input capacity		CINA	_	15	-	pF
Reference voltage: T	Reference voltage: T		_	$0.6 \times AV_{DD}$	_	V
Reference voltage: B	Reference voltage: B		_	0.2 × AV _{DD}	_	V
Reference current		lпв	-16.0	-8.0	-2.0	mA
Analog power supply current		Aldd	_	8.0	14.0	mA
Digital power supply current		DI _{DD}	-	3.0	5.0	mA

(2) Digital section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Offic
Digital "H" level output voltage	Vohd	2.4	_	DV _{DD}	V
Digital "L" level output voltage	Vold	-	_	0.4	V
Digital "H" level output current	Іон	-400	_	_	μΑ
Digital "L" level output current	Іоь	_	_	1.6	mA

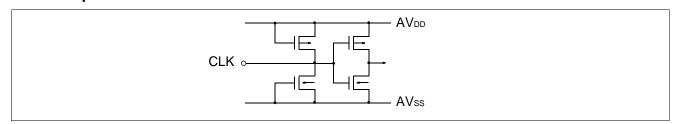
(3) Switching section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

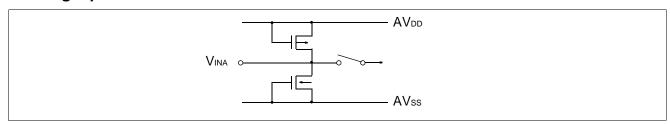
Parameter	Symbol		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Offic
Maximum conversion rate	fs	20	_	_	MSPS
Digital output delay time	tpd	0	6	25	ns

■ EQUIVALENT CIRCUIT

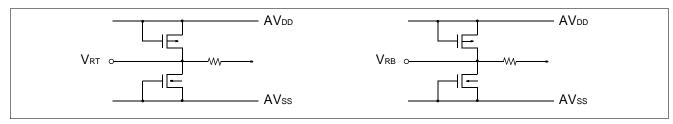
• Clock input



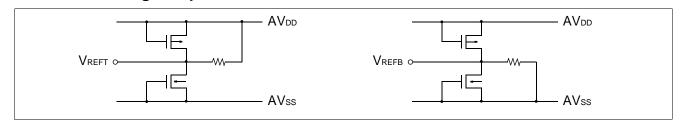
• Analog input



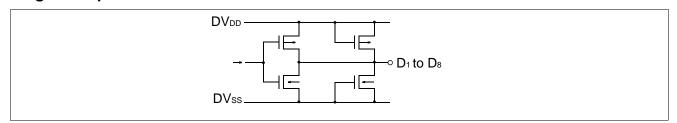
• Reference voltage input



• Reference voltage output

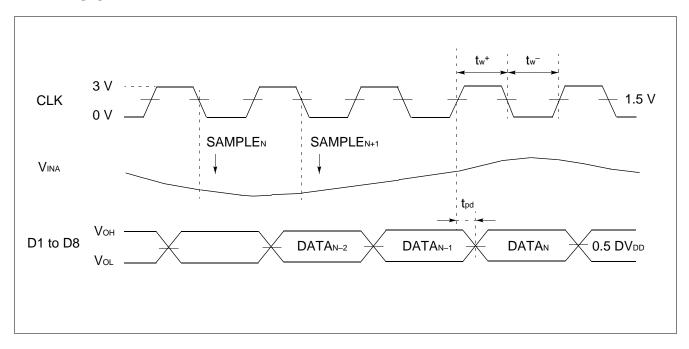


• Digital output

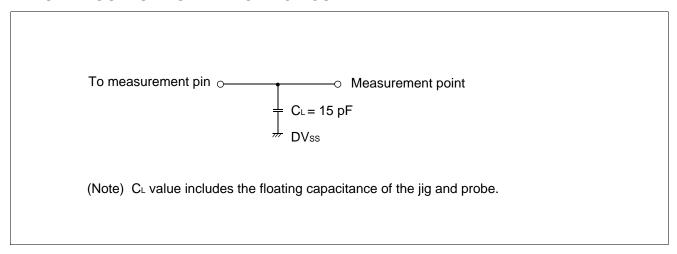


MB40C568

■ TIMING CHART



■ DIGITAL OUTPUT BUFFER LOAD CIRCUIT

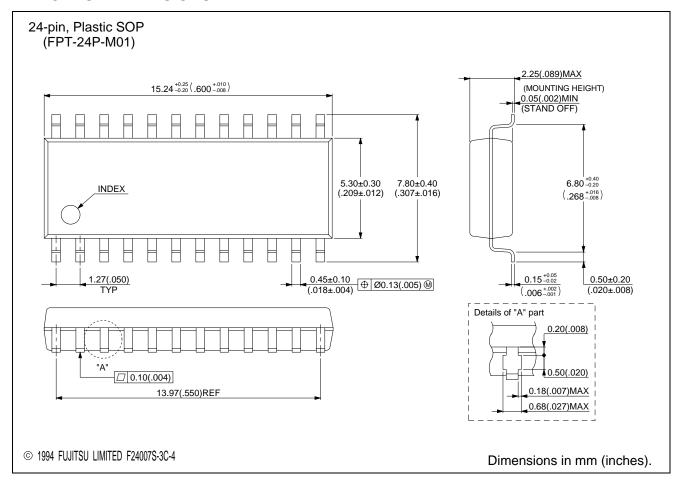


■ ORDERING INFORMATION

Part number	Package	Remarks
MB40C568PF	24-pin, Plastic SOP (FPT-24P-M01)	
MB40C568PFV	24-pin, Plastic SSOP (FPT-24P-M03)	

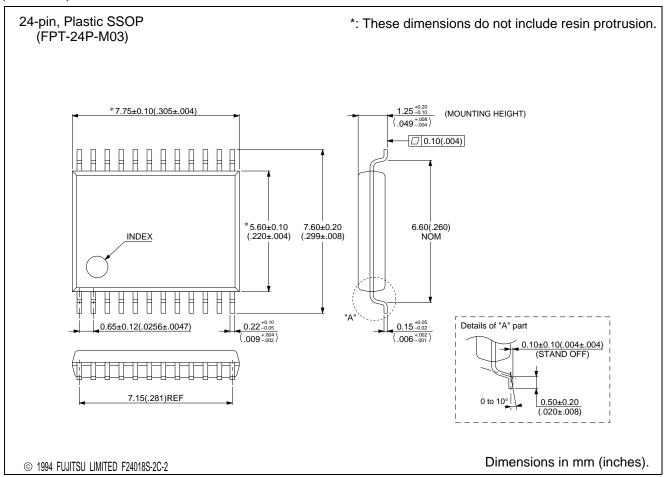
MB40C568

■ PACKAGE DIMENSIONS



(Continued)

(Continued)



FUJITSU LIMITED

For further information please contact:

Japan

FUJITSU LIMITED Corporate Global Business Support Division Electronic Devices KAWASAKI PLANT, 4-1-1, Kamikodanaka Nakahara-ku, Kawasaki-shi Kanagawa 211-88, Japan

Tel: (044) 754-3763 Fax: (044) 754-3329

North and South America

FUJITSU MICROELECTRONICS, INC. Semiconductor Division 3545 North First Street San Jose, CA 95134-1804, U.S.A.

Tel: (408) 922-9000 Fax: (408) 432-9044/9045

Europe

FUJITSU MIKROELEKTRONIK GmbH Am Siebenstein 6-10 63303 Dreieich-Buchschlag Germany

Tel: (06103) 690-0 Fax: (06103) 690-122

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE. LIMITED #05-08, 151 Lorong Chuan New Tech Park

Singapore 556741 Tel: (65) 281-0770 Fax: (65) 281-0220

All Rights Reserved.

The contents of this document are subject to change without notice. Customers are advised to consult with FUJITSU sales representatives before ordering.

The information and circuit diagrams in this document presented as examples of semiconductor device applications, and are not intended to be incorporated in devices for actual use. Also, FUJITSU is unable to assume responsibility for infringement of any patent rights or other rights of third parties arising from the use of this information or circuit diagrams.

FUJITSU semiconductor devices are intended for use in standard applications (computers, office automation and other office equipment, industrial, communications, and measurement equipment, personal or household devices, etc.).

CAUTION:

Customers considering the use of our products in special applications where failure or abnormal operation may directly affect human lives or cause physical injury or property damage, or where extremely high levels of reliability are demanded (such as aerospace systems, atomic energy controls, sea floor repeaters, vehicle operating controls, medical devices for life support, etc.) are requested to consult with FUJITSU sales representatives before such use. The company will not be responsible for damages arising from such use without prior approval.

Any semiconductor devices have inherently a certain rate of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions.

If any products described in this document represent goods or technologies subject to certain restrictions on export under the Foreign Exchange and Foreign Trade Control Law of Japan, the prior authorization by Japanese government should be required for export of those products from Japan.

F9703

© FUJITSU LIMITED Printed in Japan